

**INFORMATION DISCLOSURE
STATEMENT**Atty Docket:
Serial No.:
Applicant:
Filing Date:
Group:59684
09/848,716
CHAI ET AL.
May 3, 2001**U.S. PATENT DOCUMENTS**

Examiner Initials		Document Number	Date	Name	Class	Sub Class	Filing Date
Bm	AA	6,163,099	12/19/00	Kadota et al.	310	313A	
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						

FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Sub Class	Translation
	AL						

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)

Bm	AM	Chai et al., 1999 Joint Meeting EFTF-IEEE IFCS, <i>Growth of High Quality Single Domain Crystals of Langasite Family Compounds</i> , Crystal Photonics, Inc., pages 821-828					
	AN	Mill et al., 1999 Joint Meeting EFTF-IEEE IFCS, <i>Synthesis, Growth and some Properties of Single Crystals with the $\text{Ca}_2\text{Ga}_2\text{Ge}_4\text{O}_{14}$ Structure</i> , Moscow State University, pages 829-834					
	AO	Takeda et al., <i>Synthesis and Characterization of $\text{Sr}_3\text{TaGa}_3\text{Si}_2\text{O}_{14}$ Single Crystals</i> , Materials Research Bulletin 35 (2000), pages 245-252					
	AP	Chai et al., <i>A New Class of Ordered Langasite Structure Compounds</i> , Crystal Photonics, Inc., CREOL, University of Central Florida, 2000, pages 163-168					
	AQ						
	AR						

EXAMINER:

Pete Huy

DATE CONSIDERED:

3/7/02

***EXAMINER:** Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.